

Technical Data Data Sheet N1302, Rev. - **Green Products**

SDURF30120CT(CTR) ULTRAFAST PLASTIC RECTIFIER

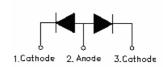
Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- · Free wheeling diode in converters and motor control circuits
- · Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

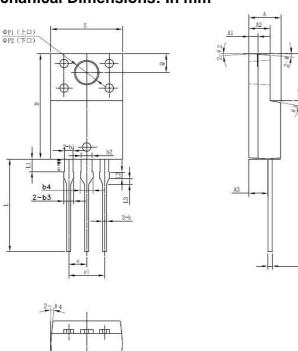
- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

SDURF30120CT



SDURF30120CTR

Mechanical Dimensions: In mm



SYMBOL	MIN.	TYP.	MAX.
Α	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	1.10	0.60 1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
С	0.55	0.60	0.75
D E	14.80	15.00	15.20
E	9.96	10.16	10.36
е		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L1 L2 L3	0.60	0.80	1.00
ΦP1(上口)	3.30	3.50	3.70
ΦP2 (下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2 Θ3 Θ4		4°	
Θ3		10°	
		5°	
Θ5		5°	

ITO-220AB

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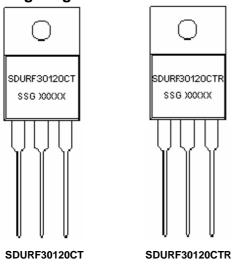
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Marking Diagram:



Where XXXXX is YYWWL

SDUR = Device Type F = Package Type

30 = Forward Current (30A) 120 = Reverse Voltage (1200V)

CT/CTR = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Package	Shipping
ITO-220AB	50pcs / tube
	<u> </u>

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	1200	V
Average Rectified Forward Current	I _{F (AV)}	Rated Vr ,@Tc=125℃	30	Α
Max. Peak One Cycle Non- Repetitive Surge Current (Per leg)	I _{FSM}	8.3ms, Half Sine pulse	90	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V_{F1}	@ 15A, Pulse, T _J = 25°C	2.75	V
	V_{F2}	@ 15A, Pulse, T _J = 150°C	1.79	V
Max. Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	100	μA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 150$ °C	0.5	mA
Max. Reverse Recovery Time	t _{rr}	I_F =1A, -di/dt=100A/us, V_R =30V, and T_J = 25°C	50	ns

 $^{^{\}star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	°C
Max. Storage Temperature	T_{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	5.0	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		

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